

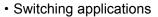
# **Isc N-Channel MOSFET Transistor**

# FMR09N90E

#### FEATURES

- With TO-3PML package
- · Low input capacitance and gate charge
- · Low gate input resistance
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

### APPLICATIONS





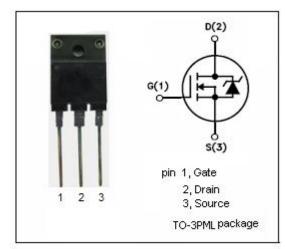
Power management

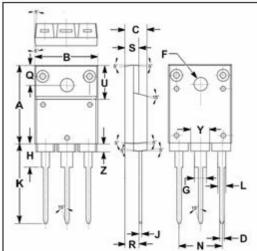
## • ABSOLUTE MAXIMUM RATINGS(T<sub>a</sub>=25°C)

SYMBOL	PARAMETER	VALUE	UNIT	
V <sub>DSS</sub>	Drain-Source Voltage	900	V	
V <sub>GSS</sub>	Gate-Source Voltage	±30	V	
I <sub>D</sub>	Drain Current-Continuous	9	А	
I <sub>DM</sub>	Drain Current-Single Pulsed	36	А	
P <sub>D</sub>	Total Dissipation @T <sub>C</sub> =25℃	100	W	
Tj	Max. Operating Junction Temperature	150	°C	
T <sub>stg</sub>	Storage Temperature	-55~150	$^{\circ}\!\mathbb{C}$	

## • THERMAL CHARACTERISTICS

SYMBOL	PARAMETER		UNIT	
Rth(ch-c)	Channel-to-case thermal resistance	1.25	°C/W	
Rth(ch-a)	Channel-to-ambient thermal resistance	62.5	°C/W	





	mm	
DIM	MIN	MAX
Α	19.90	20.10
В	15.75	16.10
С	5.50	5.70
D	0.90	1.10
F	3.30	3.50
G	2.90	3.20
Н	5.90	6.10
J	0.595	0.70
K	21.10	22.50
L N	1.90	2.25
	10.80	11.00
0	4.90	5.10
R	3.75	3.95
S	3.20	3.60
U	9.90	10.10
Υ	4.20	4.90
Z	1.90	2.10



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### **ELECTRICAL CHARACTERISTICS**

T<sub>C</sub>=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V; I <sub>D</sub> = 0.25mA	900			V
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> =V <sub>GS</sub> ; I <sub>D</sub> =0.25mA	3.5		4.5	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> = 10V; I <sub>D</sub> =4.5A		1.16	1.4	Ω
I <sub>GSS</sub>	Gate-Source Leakage Current	V <sub>GS</sub> = ±30V;V <sub>DS</sub> = 0V			±0.1	μА
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> =900V; V <sub>GS</sub> = 0V;Tc=25℃ V <sub>DS</sub> =720V; V <sub>GS</sub> = 0V;Tc=25℃			25 250	μ <b>А</b>
V <sub>SDF</sub>	Diode forward voltage	I <sub>SD</sub> =9A, V <sub>GS</sub> = 0 V			1.35	V

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